Product Datasheet Product ID: BMBP23R25/6R5-6DA



EC MICROWAVE

The door to the RF world

Thin film ceramic Filte

BMBP23R25/6R5-6DA

Precautions

1. The chip is recommended sub-cavity use, both sides of the side wall from about 0.2mm, surface distance Cover about 3mm, the chip ports are interchangeable;

2. Chip recommended low-stress conductive adhesive (such as ME8456) bonding;

3. Chip should be installed in Kovar (recommended) or molybdenum copper with ceramic thermal expansion coefficient(6.7ppm / $^{\circ}$ C) on the carrier, the carrier thickness \geq 0.2mm;

4 circuit board micro-chip wire bonding connection, it is recommended microstrip bonding at mining T-type structure to match, T-size as right

Features

high-precision film processing technology	
high performance, low temperature drift, high power	
Ceramic substrate, 50Ω coplanar waveguide output	
Gold wire bonding, suitable for multi-chip integrated module applications	

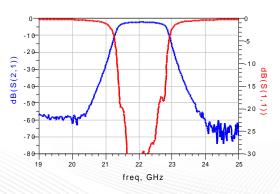
Environmental parameters

Working temperature	-55°C~+85°C
storage temperature	-55°C~+125°C
Maximum input power	35dBm

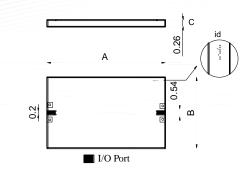
Electrical Specifications

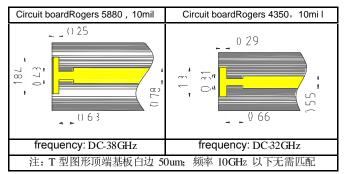
Center frequency(f0)	23.25
Passband frequency range (GHz)	20.0-26.5
Band fluctuations (dB)	1
Center insertion loss (dB)	2
Return loss (dB)	15
Band attenuation (dB)	≥ 40@ 15.2 GHz ≥ 40@32.3GHz

Band rejection & Return loss VS frequency (TA=25°C)

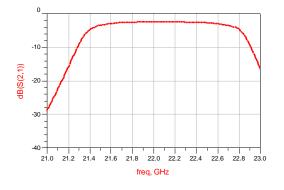


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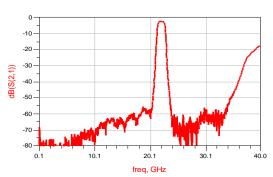




Passband loss VS frequency (T_A=25°C)



Distal inhibition VS frequency $(T_A=25^{\circ}C)$



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